

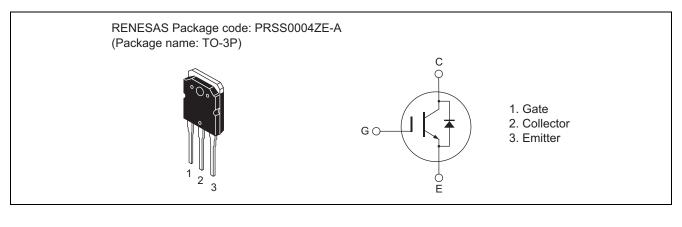
# RJH60D6DPK

Silicon N Channel IGBT Application: Inverter

# Features

- High breakdown-voltage
- Low on-voltage
- Built-in diode

# Outline



# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item		Symbol	Ratings	Unit	
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	600	V	
Gate to emitter voltage		V <sub>GES</sub>	±30	V	
Collector current	Tc = 25°C	lc	80	А	
	Tc = 100°C	Ιc	40	А	
Collector peak current		ic(peak) <sup>Note1</sup>	160	А	
Collector to emitter diode forward current		i <sub>DF</sub>	30	А	
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) <sup>Note1</sup>	120	А	
Collector dissipation		P <sub>C</sub> <sup>Note2</sup>	260	W	
Junction to case thermal impedance		θj-c <sup>Note2</sup>	0.48	°C/W	
Junction temperature		Tj	150	С°	
Storage temperature		Tstg	-55 to +150	°C	

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc = 25°C

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# **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I <sub>CES</sub> / I <sub>R</sub>	_	_	100	μΑ	V <sub>CE</sub> = 600 V, V <sub>GE</sub> = 0
/ Diode reverse current						
Gate to emitter leak current	I <sub>GES</sub>	—	—	±1	μA	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$
Gate to emitter cutoff voltage	V <sub>GE(off)</sub>	4.0	_	6.0	V	$V_{CE}$ = 10 V, I <sub>C</sub> = 1 mA
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	1.6	2.2	V	$I_{C}$ = 40 A, $V_{GE}$ = 15 V <sup>Note3</sup>
	V <sub>CE(sat)</sub>	_	1.8	—	V	$I_{C}$ = 80 A, $V_{GE}$ = 15 V <sup>Note3</sup>
Input capacitance	Cies	_	2500	_	pF	V <sub>CE</sub> = 25 V
Output capacitance	Coes	_	160	_	pF	V <sub>GE</sub> = 0
Reveres transfer capacitance	Cres	_	80	_	pF	f = 1 MHz
Total gate charge	Qg	_	104	_	nC	V <sub>GE</sub> = 15 V
Gate to emitter charge	Qge	_	15	_	nC	V <sub>CE</sub> = 300 V
Gate to collector charge	Qgc	_	43	_	nC	I <sub>C</sub> = 30 A
Switching time	t <sub>d(on)</sub>	_	50	_	ns	I <sub>C</sub> = 40 A
	tr	_	90	_	ns	R <sub>L</sub> = 7.5 Ω
	t <sub>d(off)</sub>	_	150		ns	V <sub>GE</sub> = 15 V
	t <sub>f</sub>	_	90	—	ns	Rg = 5 Ω

FRD Forward voltage	VF	_	1.8	2.3	V	$I_F = 30 A^{Note3}$
FRD reverse recovery time	trr	—	100	—	ns	I <sub>F</sub> = 30 A
						di <sub>F</sub> /dt = 100 A/µs

Notes: 3. Pulse test.

4. Under development. - The specifications potentially be changed without notice

# Package Dimension

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]	
TO-3P	SC-65	PRSS0004ZE-A	TO-3P / TO-3PV	5.0g	Unit: mm
	<u>1.6</u> <u>1.4 Ma</u>	15.6 ± 0.3	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	4.8 ± 0.2 1.5 0.6 ± 0.2	
	<u>5.45 ± (</u>		<u>.0</u> <u>.0</u> <u></u> <u>5.45 ± 0.5</u>		

# **Ordering Information**

Part No.	Quantity	Shipping Container		
RJH60D6DPK-00-T0	360 pcs	Box (Tube)		

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